502610347 12/20/2013

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2

EPAS ID: PAT2656761

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
THOMAS HOFFMANN	04/24/2012
PUSHKAR RANADE	04/24/2012
LUCIAN SHIFREN	04/24/2012
SCOTT E. THOMPSON	04/24/2012

RECEIVING PARTY DATA

Name:	SUVOLTA, INC.
Street Address:	130 KNOWLES DRIVE, SUITE D
City:	LOS GATOS
State/Country:	CALIFORNIA
Postal Code:	95032

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	13624449

CORRESPONDENCE DATA

Fax Number: (202)371-2540 Phone: 202.371.2600

Email: kchang@skgf.com, rwemer@skgf.com

Correspondence will be sent via US Mail when the email attempt is unsuccessful.

Correspondent Name: STERNE, KESSLER, GOLDSTEIN & FOX P.L.L.C

Address Line 1: 1100 NEW YORK AVENUE, N.W.

Address Line 4: WASHINGTON, DISTRICT OF COLUMBIA 20005

ATTORNEY DOCKET NUMBER:	3139.0020002
NAME OF SUBMITTER:	RAYMOND J. WERNER
Signature:	/Raymond J. Werner Reg. No. 34,752/
	PATENT

502610347 REEL: 031827 FRAME: 0938

OP \$40,00 13624449

Date:	12/20/2013
Total Attachments: 5 source=3139.0020002 Assignment#page1.t source=3139.0020002 Assignment#page2.t source=3139.0020002 Assignment#page3.t source=3139.0020002 Assignment#page4.t source=3139.0020002 Assignment#page5.t	if if

ASSIGNMENT

WHEREAS, I, the undersigned inventor (or one of the undersigned joint inventors), of residence as listed, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made, said application having been executed on the date set forth below; and

WHEREAS, SUVOLTA, INC. (hereinafter referred to as "Assignee"), a Delaware corporation, with an address of 130 Knowles Drive, Suite D, Los Gatos, California 95032, desires to acquire my entire right, title and interest in and to the invention, and in and to the said application and any Letters Patent that may issue thereon;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, I assign to Assignee, all right, title and interest in and to said invention and in and to said application and all patents which may be granted therefor, and all provisional, divisions, reissues, continuations, continuations-in-part and extensions thereof; and I hereby authorize and request the Commissioner of Patents and Trademarks to issue all patents for said invention, or patents resulting therefrom, insofar as my interest is concerned, to Assignee.

I also assign to Assignee, all right, title and interest to the invention disclosed in said application throughout the world, including the right to file applications and obtain patents, utility models, industrial models and designs for said invention in its own name throughout the world including all rights to publish cautionary notices reserving ownership of said invention and all rights to register said invention in appropriate registries; and I further agree to execute any and all powers of attorney, applications, assignments, declarations, affidavits, and any other papers in connection therewith necessary to perfect such right, title and interest in Assignee.

I will communicate to Assignee any facts known to me respecting any improvements; and, at the expense of Assignee, I will testify in any legal proceedings, sign all lawful papers, execute all provisional, divisional, continuation, continuation-in-part, reissue and substitute applications, make lawful oaths and declarations, and generally do everything possible to vest title in Assignee and to aid Assignee to obtain and enforce proper protection for said invention in all countries.

This Assignment shall be binding on the parties' successors, assigns and legal representatives.

Title of Invention:	MULTIPLE TRANSISTOR TYPES FORMED IN A
	COMMON EPITAXIAL LAYER BY DIFFERENTIAL

OUT-DIFFUSION FROM A DOPED UNDERLAYER

Signature of Inventor:
Full name of inventor:
Thomas Hoffmann

Residence: San Jose, California 95124

Title of Invention:	MULTIPLE TRANSISTOR TYPES FORMED IN A COMMON EPITAXIAL LAYER BY DIFFERENTIAL OUT-DIFFUSION FROM A DOPED UNDERLAYER
Signature of Inventor: Full name of inventor:	Pushkar Ranade
Residence:	Los Gatos, California 95032
Date:	4/24/12

MULTIPLE TRANSISTOR TYPES FORMED IN A Title of Invention:

COMMON EPITAXIAL LAYER BY DIFFERENTIAL

OUT-DIFFUSION FROM A DOPED UNDERLAYER

Signature of Inventor: Full name of inventor:

Residence:

San Jose, California 95118

Date:

Title of Invention:

MULTIPLE TRANSISTOR TYPES FORMED IN A COMMON EPITAXIAL LAYER BY DIFFERENTIAL **OUT-DIFFUSION FROM A DOPED UNDERLAYER**

Signature of Inventor: Full name of inventor:

Scott E. Thompson

Residence:

Gainesville, Florida 32607

4/24/2012

Date:

PATENT REEL: 031827 FRAME: 0944

RECORDED: 12/20/2013